- Inputs Are TTL-Voltage Compatible
- Flow-Through Architecture Optimizes
  PCB Layout
- Center-Pin V<sub>CC</sub> and GND Configurations Minimize High-Speed Switching Noise
- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

#### description

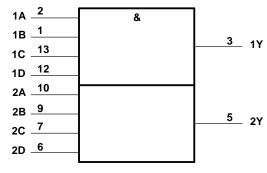
These devices contain two independent 4-input AND gates. They perform the Boolean functions  $Y = A \cdot B \cdot C \cdot D$  or  $Y = \overline{A} + \overline{B} + \overline{C} + \overline{D}$  in positive logic.

The 54ACT11021 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to 125°C. The 74ACT11021 is characterized for operation from  $-40^{\circ}$ C to  $85^{\circ}$ C.

## FUNCTION TABLE (each gate)

l		INP		ОИТРИТ					
	Α	В	С	D	Y				
I	Н	Н	Н	Н	Н				
l	L	Χ	Χ	Х	L				
l	Χ	L	Χ	Χ	L				
١	Χ	Χ	L	Х	L				
	Χ	Χ	Χ	L	L				

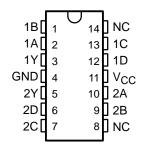
#### logic symbol†



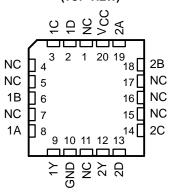
<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the D, J, and N packages.

#### 54ACT11021 . . . J PACKAGE 74ACT11021 . . . D OR N PACKAGE (TOP VIEW)

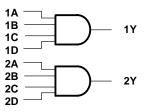


# 54ACT11021 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

### logic diagram (positive logic)



EPIC is a trademark of Texas Instruments Incorporated.



### 54ACT11021, 74ACT11021 DUAL 4-INPUT POSITIVE-AND GATES

SCAS012B - D2957, JULY 1987 - REVISED APRIL 1993

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, V <sub>O</sub> (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ )	±20 mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ or $V_O > V_{CC}$ )	$\dots \dots \pm 50 \text{ mA}$
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ )	±50 mA
Continuous current through V <sub>CC</sub> or GND	±100 mA
Storage temperature range	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### recommended operating conditions

		54ACT	11021	74ACT	UNIT	
		MIN MAX		MIN	MAX	UNII
VCC	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
VIL	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	VCC	0	VCC	V
Vo	Output voltage	0	VCC	0	VCC	V
ІОН	High-level output current		-24		-24	mA
l <sub>OL</sub>	Low-level output current		24		24	mA
Δt/Δν	Input transition rise or fall rate	0	10	0	10	ns/V
TA	Operating free-air temperature	-55	125	- 40	85	°C

SCAS012B - D2957, JULY 1987 - REVISED APRIL 1993

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	vcc	T,	Δ = 25°C	;	54AC	Γ11021	74ACT11021		UNIT
PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
	I <sub>OH</sub> = – 50 μA	4.5 V	4.4			4.4		4.4		v
		5.5 V	5.4			5.4		5.4		
Vari	I <sub>OH</sub> = – 24 mA	4.5 V	3.94			3.7		3.8		
VOH	10H = - 24 IIIA	5.5 V	4.94			4.7		4.8		
	$I_{OH} = -50 \text{ mA}^{\ddagger}$	5.5 V				3.85				
	I <sub>OH</sub> = - 75 mA <sup>‡</sup>	5.5 V						3.85		
	I <sub>OL</sub> = 50 μA	4.5 V			0.1		0.1		0.1	
	ΙΟΓ = 30 μΑ	5.5 V		0.1		0.1		0.1		
V	I <sub>OL</sub> = 24 mA	4.5 V			0.36		0.5		0.44	٧
VOL		5.5 V			0.36		0.5		0.44	
	$I_{OL} = 50 \text{ mA}^{\ddagger}$	5.5 V					1.65			
	I <sub>OL</sub> = 75 mA <sup>‡</sup>	5.5 V							1.65	
lį	$V_I = V_{CC}$ or GND	5.5 V			± 0.1		± 1		± 1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		80		40	μΑ
Δl <sub>CC</sub> §	One input at 3.4 V, Other inputs at GND or V <sub>CC</sub>	5.5 V			0.9		1		1	mA
Ci	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		3.5						pF

<sup>‡</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то	T,	4 = 25°C	;	54ACT	11021	74ACT	11021	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
<sup>t</sup> PLH	Any	V	1.5	6.7	8.8	1.5	10.4	1.5	9.8	
<sup>t</sup> PHL		ſ	1.5	5.4	8.3	1.5	9.5	1.5	8.9	ns

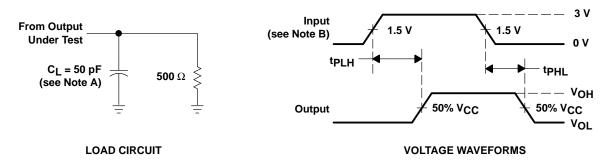
## operating characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance per gate	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	37	pF

<sup>§</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or VCC.

SCAS012B - D2957, JULY 1987 - REVISED APRIL 1993

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f = 3 \text{ ns}$ ,  $t_f = 3 \text{ ns}$ .
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

#### **IMPORTANT NOTICE**

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.

Copyright © 1996, Texas Instruments Incorporated